# NSN 5962-01-276-1200

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## Body Length:

1.290 inches

## Body Width:

Between 0.500 inches and 0.610 inches

## **Body Height:**

Between 0.150 inches and 0.210 inches

## **Operating Tempurature Range:**

-55.0/+125.0 degrees celsius

## Storage Tempurature Range:

-65.0/+150.0 degrees celsius

## **Features Provided:**

Hermetically sealed and burn in and programmable and high speed and w/enable

## **Inclosure Material:**

Ceramic

#### Inclosure Configuration:

Dual-in-line

## **Output Logic Form:**

Transistor-transistor logic

## Input Circuit Pattern:

14 input

Case Outline Source And Designator:

D-3 mil-m-38510

## **Terminal Surface Treatment:**

Solder

## Voltage Rating And Type Per Characteristic:

7.0 volts power source

## **Time Rating Per Chacteristic:**

120.00 nanoseconds propagation delay time, low to high level output and 120.00 nanoseconds propagation delay time, high to low level output

#### Memory Device Type:

Rom

#### Memory Capacity:

Unknown

### Test Data Document:

96906-mil-std-883 standard (includes industry or association standards, individual manufactureer standards, etc.).

### Terminal Type And Quantity:

24 printed circuit

### Shelf Life:

N/a

#### Unit Of Measure:

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#### Demilitarization:

Yes - demil/mli

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